M

Notice of Allowability	Application No.	Applicant(s)		
	10/669,616	MILLER, BRIAN	MILLER, BRIAN	
	Examiner	Art Unit		
	Rodney G. McDonald	1753		
The MAILING DATE of this communication appearance All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIOF of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this a or other appropriate communicati IGHTS. This application is subject	application. If not include on will be mailed in due	led course. <b>THIS</b>	
1. This communication is responsive to <u>Amendment filed 5-9-</u>	<u>-06</u> .			
2. X The allowed claim(s) is/are <u>1-3,6,7,10-14,17,19-22 and 24-</u>	<u>-30</u> .			
<ul> <li>3. Acknowledgment is made of a claim for foreign priority una)  All b)  Some* c)  None of the:  1. Certified copies of the priority documents have  2. Certified copies of the priority documents have  3. Copies of the certified copies of the priority documents not  International Bureau (PCT Rule 17.2(a)).  * Certified copies not received:  Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.</li> <li>4. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give  5. CORRECTED DRAWINGS (as "replacement sheets") mus  (a) including changes required by the Notice of Draftspers  1) hereto or 2) to Paper No./Mail Date  [b) including changes required by the attached Examiner's  Paper No./Mail Date  Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in the compatition of the population of the deponant of the population of the population of the deponant of the population of the population of the deponant of the population of the population of the deponant of the population of the deponant of the population of the population of the deponant of the population of the deponant of the population of the population of the deponant of the population of the priority document of the priority documen</li></ul>	e been received. e been received in Application No. cuments have been received in thi of this communication to file a rep IENT of this application.  itted. Note the attached EXAMINE es reason(s) why the oath or decla st be submitted. con's Patent Drawing Review (PTo. s Amendment / Comment or in the 1.84(c)) should be written on the draw the header according to 37 CFR 1.12 sit of BIOLOGICAL MATERIAL	is national stage applications is national stage application is deficient.  O-948) attached  Office action of wings in the front (not the 11d).  must be submitted.	equirements  NOTICE OF	
Attachment(s)  1.  Notice of References Cited (PTO-892)  2.  Notice of Draftperson's Patent Drawing Review (PTO-948)  3.  Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date  4.  Examiner's Comment Regarding Requirement for Deposit of Biological Material	5.	Patent Application (PT ry (PTO-413), Pate dment/Comment	owance	

## **REASONS FOR ALLOWANCE**

The following is an examiner's statement of reasons for allowance:

Claims 1-3 are allowable over the prior art of record because the prior art of record does not teach a method for removing a material covering an alignment on a substrate including directing a non-liquid metal ion beam at the material covering an alignment mark, the ion beam having a beam current greater than 300 nanoamps and directed at an oblique angle relative to the surface of the substrate; and removing the material by ion beam sputtering, the ion beam maintaining a substantially identical oblique angle relative to the surface of the substrate while material is removed by ion beam sputtering.

Claims 6, 7, 10-13 and 30 are allowable over the prior art of record because the prior art of record does not teach a method for removing material covering an alignment mark on a substrate including directing a focused ion beam of noble gas ions at the material covering an alignment mark; the focused ion beam being directed at the substrate at an angle of between 40 degrees and 80 degrees relative to the substrate surface normal; and removing the material by charged particle beam sputtering without using an etch assisting gas.

Claims 14, 17 and 19-22 are allowable over the prior art of record because the prior art of record does not teach an apparatus for removing a material covering an alignment mark on a substrate including a noble gas ion beam system having a noble gas ion source suitable for emitting a noble gas ion beam, the source oriented at an oblique angle relative to the substrate surface normal, an optical system to focus the

Art Unit: 1753

noble gas ion beam, and a computer controlled beam deflector to portion the noble gas ion beam and computer accessible memory having computer instructions for directing a charge particle beam at material covering an alignment mark; and removing the material by charged particle beam sputtering.

Claims 24-29 are allowable over the prior art of record because the prior art of record does not teach a method for removing a material covering an alignment mark on a substrate including directing a non-liquid metal ion beam at the material covering an alignment mark, the ion beam having a beam current greater than 300 nanoamps and the optical axis forming an oblique angle relative to the substrate surface normal; and removing the material by ion beam sputtering without using an etch assisting gas.

The closest prior art of record fails to teach utilizing a non-liquid metal or noble gas ion source for sputtering material to expose the alignment mark. Furthermore, the closest prior art of record fails to disclose utilizing the beam current limitations of the claims for the ion source for sputtering material to expose the alignment mark.

Furthermore, the closest prior art of record fails to disclose an oblique angle for sputtering material to expose the alignment mark.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Art Unit: 1753

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Rodney G. McDonald whose telephone number is 571-272-1340. The examiner can normally be reached on M- Th with Every other Friday off.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nam X. Nguyen can be reached on 571-272-1342. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Rodney G. McDonald Primary Examiner Art Unit 1753

RM July 31, 2006